Notice of Allowability	Application No.	Applicant(s)
	10/686,106	ти, кио-сні
	Examiner	Art Unit
	PHUC T. DANG	2818
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308. 1. This communication is responsive to election filed January 4, 2005. 2. The allowed claim(s) is/are 1-21. 3. The drawings filed on 15 October 2003 are accepted by the Examiner. 4. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).		
a) All b) Some* c) None of the:		
1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No		
3. Copies of the certified copies of the priority documents have been received in this national stage application from the		
International Bureau (PCT Rule 17.2(a)).		
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.		
6. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.		
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached		
1) hereto or 2) to Paper No./Mail Date		
(b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date		
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).		
7. ☐ DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.		
Attachment(s)		
1. Notice of References Cited (PTO-892)		Patent Application (PTO-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Da	•
3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 101503		ment/Comment ent of Reasons for Allowance
 Examiner's Comment Regarding Requirement for Deposit of Biological Material 	9.	on Neusons for Allowance
C. Diological material	<u></u> .	
PHUCT. DANG PD		
PRIMARY EXAMINER Sangphur		
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DETAILED ACTION

Examiner's Amendment

1. An Examiner's Amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 C.F.R.

1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the Issue Fee.

Authorization for this Examiner's Amendment was given in the telephone interview with Roger C. Knapp on January 27, 2005 as follows:

- 2. In claim 10, lines 6-7, insert "of" before "a split-gate transistor".
- 3. Claims 22-24 have been canceled.

Claims 1-21 are pending in the present application at this time for examination.

Examiner's Statement of Reasons for Allowance

- 4. Claims 1-21 are allowed.
- 5. The following is an examiner's statement of reasons for allowance:

With respect to claims 1-9, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method of forming a memory, the method comprising a step of forming a poly-oxide layer of a split-gate transistor in the non-volatile memory region.

With respect to claims 10-21, the prior art of record, taken alone or in combination, fails to teach or reasonably suggests a method of forming a memory, the method comprising a step of oxidizing a first portion of the first polysilicon layer to form a poly-oxide layer of a split-gate transistor.

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Any comments considered necessary by applicant must be submitted no later than the 6. payment of the issue fee and, to avoid processing delays, should preferably accompany the issue

fee. Such submission should be clearly labeled "Comments on Statement of Reasons for

Allowance".

7. Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Phuc T. Dang whose telephone number is (571) 272-1776. The examiner

can normally be reached on 8:00 am-5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, 8.

David C. Nelms can be reached on (571) 272-1787. The fax phone numbers for the organization

where this application or proceeding is assigned are 703-872-9306 for regular communications

and After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703-308-0956.

Phuc T. Dang

PD Langshir

Primary Examiner

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